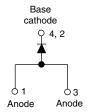




Vishay Semiconductors

Schottky Rectifier, 3.0 A





PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)					
I _{F(AV)}	3.0 A					
V _R	20 V, 30 V, 40 V					
V _F at I _F	0.49 V					
I _{RM}	20 mA at 125 °C					
T _J max.	150 °C					
Diode variation	Single die					
E _{AS}	8 mJ					

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION

The VS-MBRD320PbF, VS-MBRD330PbF, VS-MBRD340PbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform	3.0	А					
V _{RRM}		20 to 40	V					
I _{FSM}	t _p = 5 µs sine	490	А					
V _F	3 Apk, T _J = 125 °C	0.49	V					
T _J		- 40 to 150	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-MBRD320PbF	VS-MBRD330PbF	VS-MBRD340PbF	UNITS		
Maximum DC reverse voltage	V_{R}	20	30	40	V		
Maximum working peak reverse voltage	V_{RWM}	V _{RWM} 20	30	40	V		

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 133 °C, re	3.0						
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	Α				
	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75					
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero i Frequency limited by T_J maximum	1.0	Α					

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VS-MBRD320PbF, VS-MBRD330PbF, VS-MBRD340PbF

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS		
		3 A	T _J = 25 °C	0.48	0.6	· V		
Maximum forward voltage drop	V _{FM} ⁽¹⁾	6 A	11 = 23 0	0.58	0.7			
See fig. 1	V FM (*)	3 A	T _{.1} = 125 °C	0.41	0.49			
		6 A	1J = 125 C	0.55	0.625			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm R}$ = Rated $V_{\rm R}$	0.02	0.2	mA		
See fig. 2		T _J = 125 °C	v _R = nateu v _R	10.7	20	IIIA		
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		189	-	pF		
Typical series inductance	L _S	Measured lead to lead 5 n	5.0	-	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	-	10 000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperature range	T _J ⁽¹⁾		- 40 to 150	°C			
Maximum storage temperature range	T _{Stg}		- 40 to 175	1 -0			
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0	2000			
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W			
Approximate weight			0.3	g			
Approximate weight			0.01	oz.			
			MBRD320				
Marking device		Case style D-PAK (similar to TO-252AA)	MBRD330				
			MBRD340				

Note

$$^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$$





Schottky Rectifier, 3.0 A

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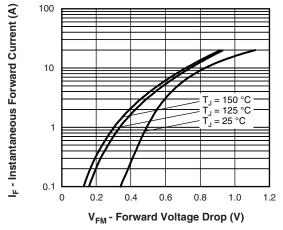


Fig. 1 - Maximum Forward Voltage Drop Characteristics

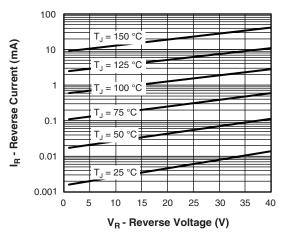


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

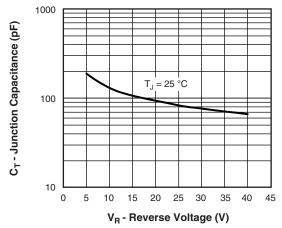


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

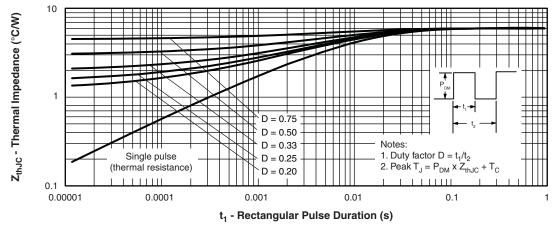


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

VS-MBRD320PbF, VS-MBRD330PbF, VS-MBRD340PbF

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Schottky Rectifier, 3.0 A



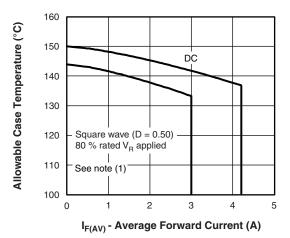


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

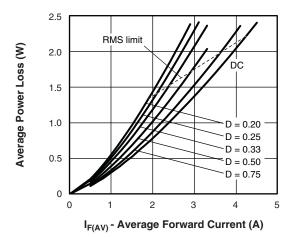


Fig. 6 - Forward Power Loss Characteristics

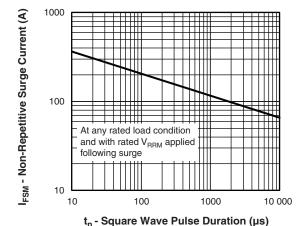


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



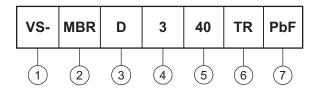
VS-MBRD320PbF, VS-MBRD330PbF, VS-MBRD340PbF

Schottky Rectifier, 3.0 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Schottky MBR series

D = TO-252AA (D-PAK)

Current rating (3 = 3 A)

20 = 20 V30 = 30 VVoltage ratings -40 = 40 V

• None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

7 PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					

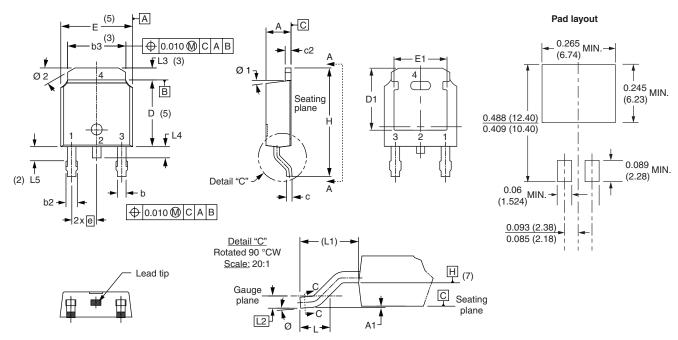
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Vishay Semiconductors

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



	SYMBOL	MILLIM	IETERS	INCHES		NOTES		SYMBOL	MILLIN	
		MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	
	Α	2.18	2.39	0.086	0.094			е	2.29	
	A1	-	0.13	-	0.005			Н	9.40	
	b	0.64	0.89	0.025	0.035			L	1.40	
	b2	0.76	1.14	0.030	0.045			L1	2.74	
	b3	4.95	5.46	0.195	0.215	3		L2	0.51	
	С	0.46	0.61	0.018	0.024			L3	0.89	
	c2	0.46	0.89	0.018	0.035			L4	-	
	D	5.97	6.22	0.235	0.245	5		L5	1.14	
	D1	5.21	-	0.205	-	3		Ø	0°	
	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	
	E1	4.32	-	0.170	-	3		Ø2	25°	

SYMBOL	MILLIMETERS		INC	NOTES	
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51	BSC	0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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